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April 2015

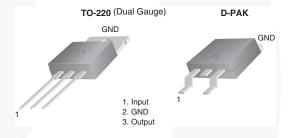
KA78XXE / KA78XXAE 3-Terminal 1 A Positive Voltage Regulator

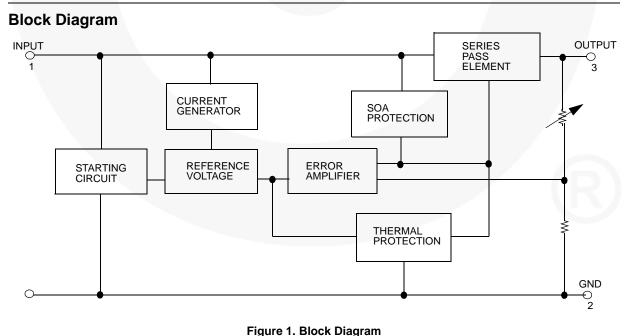
Features

- · Output Current up to 1 A
- Output Voltages of 5, 6, 8, 9, 10, 12, 15, 18, 24 V
- Thermal Overload Protection
- · Short-Circuit Protection
- Output Transistor Safe Operating Area Protection

Description

The KA78XXE / KA78XXAE series of three-terminal positive regulators is available in the TO-220 / D-PAK package with several fixed-output voltages, making them useful in a wide range of applications. Each type employs internal current limiting, thermal shut-down, and safe operating area. If adequate heat sinking is provided, they can deliver over 1 A output current. Although designed primarily as fixed-voltage regulators, these devices can be used with external components for adjustable voltages and currents.

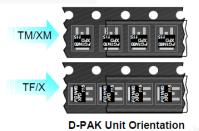




Ordering Information

Product Number	Output Voltage Tolerance ⁽¹⁾	Package	Operating Temperature	Parking Method
KA7805ETU				
KA7806ETU				
KA7808ETU				
KA7809ETU				
KA7810ETU		TO-220 (Dual Gauge)		Rail
KA7812ETU				
KA7815ETU	±4%	-40°C to +125°C	40°C to 1125°C	
KA7818ETU	±4 /0			
KA7824ETU				
KA7805ERTF				
KA7805ERTM				
KA7808ERTM		D-PAK ⁽²⁾		Tape and Reel
KA7809ERTM				
KA7812ERTM				
KA7805AETU				
KA7809AETU				
KA7810AETU	±2%	TO-220 (Dual Gauge)	0°C to +125°C	Rail
KA7812AETU	±2 /0	10-220 (Dual Gauge)	0 0 10 +125 0	IXali
KA7815AETU			\	
KA7824AETU				

- 1. Above output voltage tolerance is available at 25°C.
- 2. Refer to below figure for TM / TF Suffix for DPAK.



Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter		Value	Unit
V	Input Voltage	V _O = 5 V to 18 V	35	V
٧١	V _I Input Voltage	V _O = 24 V	40	V
$R_{\theta JC}$	Thermal Resistance Junction-Case (To	5	°C/W	
$R_{\theta JA}$	Thermal Resistance Junction-Air (TO-2	220)	65	°C/W
т	Operating Temperature Range	KA78XXE / KA78XXER	-40 to +125	- °C
T_{OPR}	Operating Temperature Name	KA78XXAE	0 to +125]
T _{STG}	Storage Temperature Range		-65 to +150	°C

Electrical Characteristics (KA7805E / KA7805ER)

Refer to test circuit, -40°C < T_J < 125°C, I_O = 500 mA, V_I =10 V, C_I= 0.33 μ F, C_O=0.1 μ F, unless otherwise specified.

Symbol	Parameter	(Conditions			Max.	Unit
		$T_J = +25^{\circ}C$		4.80	5.00	5.20	
V _O	Output Voltage	5.0 mA I_{C} $V_{I} = 7 \text{ V to } 2$	0 V	4.75	5.00	5.25	V
Regline	Line Regulation ⁽³⁾	T ±25°C	$V_1 = 7 \text{ V to } 25 \text{ V}$ $V_2 = 8 \text{ V to } 12 \text{ V}$		4.0	100.0	mV
Regime	Line Regulation				1.6	50.0	IIIV
Regload	Load Regulation ⁽³⁾	T 125°C	$I_0 = 5.0 \text{ mA to } 1.5 \text{ A}$		9	100	mV
Regioau	Load Regulation	1) = +25 C	$I_{O} = 250 \text{ mA to } 750 \text{ mA}$		4	50	1117
IQ	Quiescent Current	$T_J = +25^{\circ}C$			5	8	mA
Al-	Quiescent Current Change	$I_O = 5 \text{ mA to}$	1.0 A		0.03	0.50	mA
ΔI_{Q}	Quiescent Current Change	$V_1 = 7 \text{ V to } 2$	5 V		0.30	1.30	IIIA
$\Delta V_{O}/\Delta T$	Output Voltage Drift ⁽⁴⁾	$I_O = 5 \text{ mA}$			-0.8		mV/°C
V _N	Output Noise Voltage	f = 10 Hz to	100 kHz, T _A = +25°C		42		μV
RR	Ripple Rejection ⁽⁴⁾	f = 120 Hz, \	V _I = 8 V to 18 V	62	73		dB
V_{Drop}	Dropout Voltage	$I_O = 1 A, T_J$	= +25°C		2		V
R _O	Output Resistance ⁽⁴⁾	f = 1 kHz			15		mΩ
I _{SC}	Short-Circuit Current	$V_{I} = 35 \text{ V}, \text{ T}_{I}$	_A = +25°C		230		mA
I _{PK}	Peak Current ⁽⁴⁾	$T_{J} = +25^{\circ}C$			2.2		Α

- 3. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 4. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7806E)

Refer to test circuit, -40°C < T_J < 125°C, I_O = 500 mA, V_I = 11 V, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Symbol	Parameter	(Min.	Тур.	Max.	Unit	
		T _J = +25°C		5.75	6.00	6.25	
V _O	Output Voltage	5.0 mA I_{O} $V_{I} = 8.0 \text{ V to}$	1.0 A, P _O 15 W, 21 V	5.70	6.00	6.30	V
Regline	Line Regulation ⁽⁵⁾	T _{.1} = +25°C	V _I = 8 V to 25 V		5.0	120.0	mV
Regime	Line Regulation 7	1 1 - +23 0	V _I = 9 V to 13 V		1.5	60.0	1110
Doglood	Load Regulation ⁽⁵⁾	T _{.1} = +25°C	$I_{O} = 5 \text{ mA to } 1.5 \text{ A}$		9	120	m\/
Regload	Load Regulation 7	1j = +25 C	$I_{O} = 250 \text{ mA to } 750 \text{ mA}$		3	60	mV
IQ	Quiescent Current	$T_J = +25^{\circ}C$			5	8	mA
Al	Quiescent Current	$I_O = 5 \text{ mA to}$	1 A			0.5	mA
ΔI_{Q}	Change	V _I = 8 V to 2	5 V			1.3	IIIA
$\Delta V_{O}/\Delta T$	Output Voltage Drift ⁽⁶⁾	$I_O = 5 \text{ mA}$			-0.8		mV/°C
V _N	Output Noise Voltage	f = 10 Hz to 1	00 kHz, T _A = +25°C		45		μV
RR	Ripple Rejection ⁽⁶⁾	f = 120 Hz, \	/ _I = 9 V to 19 V	59	75		dB
V_{Drop}	Dropout Voltage	I _O = 1 A, T _J :	= +25°C		2		V
R _O	Output Resistance ⁽⁶⁾	f = 1 kHz			19		mΩ
I _{SC}	Short-Circuit Current	$V_1 = 35 \text{ V}, T_A$	_λ = +25°C		250		mA
I _{PK}	Peak Current ⁽⁶⁾	$T_J = +25^{\circ}C$			2.2		Α

- 5. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 6. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7808E / KA7808ER)

Refer to test circuit, -40°C < T_J < 125°C, I_O = 500 mA, V_I = 14 V, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Symbol	Parameter	(Conditions	Min.	Тур.	Max.	Unit
		$T_J = +25^{\circ}C$		7.7	8.0	8.3	
V _O	Output Voltage	5.0 mA I _O V _I = 10.5 V to	1.0 A, P _O 15 W, o 23 V	7.6	8.0	8.4	V
Regline	Line Regulation ⁽⁷⁾	T _J = +25°C	V _I = 10.5 V to 25 V		5	160	mV
Regilile	Line Regulation 7	1j = +25 C	V _I = 11.5 V to 17 V		2	80	IIIV
Poglood	Load Regulation ⁽⁷⁾	T _J = +25°C	$I_O = 5.0 \text{ mA to } 1.5 \text{ A}$		10	160	mV
Regload	Load Regulation 7	Io	$I_{O} = 250 \text{ mA to } 750 \text{ mA}$		5	80	IIIV
IQ	Quiescent Current	$T_J = +25^{\circ}C$	T _J = +25°C		5	8	mA
ΔI	Quiescent Current	$I_O = 5 \text{ mA to}$	1.0 A		0.05	0.50	mA
ΔI_{Q}	Change	V _I = 10.5 A to	o 25 V		0.50	1.00	IIIA
$\Delta V_{O}/\Delta T$	Output Voltage Drift ⁽⁸⁾	$I_O = 5 \text{ mA}$			-0.8		mV/°C
V _N	Output Noise Voltage	f = 10 Hz to 10	00 kHz, T _A = +25°C		52		μV
RR	Ripple Rejection ⁽⁸⁾	f = 120 Hz, \	/ _I = 11.5 V to 21.5 V	56	73		dB
V_{Drop}	Dropout Voltage	I _O = 1 A, T _J =	= +25°C		2		V
R _O	Output Resistance ⁽⁸⁾	f = 1 kHz			17		mΩ
I _{SC}	Short-Circuit Current	$V_1 = 35 \text{ V}, T_A$	_v = +25°C		230		mA
I _{PK}	Peak Current ⁽⁸⁾	$T_J = +25^{\circ}C$			2.2		Α

- 7. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 8. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7809E / KA7809ER)

Refer to test circuit, -40°C < T_J < 125°C, I_O = 500 mA, V_I = 15 V, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Symbol	Parameter	C	Conditions			Max.	Unit
		T _J = +25°C		8.65	9.00	9.35	
V _O	Output Voltage	$5.0 \text{ mA} \le I_O \le V_I = 11.5 \text{ V to}$	≤ 1.0 A, P _O ≤ 15 W, o 24 V	8.60	9.00	9.40	V
Regline	Line Regulation ⁽⁹⁾	T _{.1} = +25°C	V _I = 11.5 V to 25 V		6	180	mV
Regime	Line Regulation	1j = +25 C	V _I = 12 V to 17 V		2	90	IIIV
Boglood	Load Regulation ⁽⁹⁾	T _J = +25°C	$I_{O} = 5 \text{ mA to } 1.5 \text{ A}$		12	180	m\/
Regload	Load Regulation 7	1j = +25 C	$I_{O} = 250 \text{ mA to } 750 \text{ mA}$		4	90	mV
IQ	Quiescent Current	$T_J = +25^{\circ}C$			5	8	mA
ΔĪ	Quiescent Current	$I_O = 5 \text{ mA to}$	1.0 A			0.5	mA
ΔI_{Q}	Change	V _I = 11.5 V to	26 V			1.3	IIIA
$\Delta V_{O}/\Delta T$	Output Voltage Drift ⁽¹⁰⁾	I _O = 5 mA			-1		mV/°C
V _N	Output Noise Voltage	f = 10 Hz to 10	00 kHz, T _A = +25°C		58		μV
RR	Ripple Rejection ⁽¹⁰⁾	f = 120 Hz, V	_I = 13 V to 23 V	56	71		dB
V_{Drop}	Dropout Voltage	I _O = 1 A, T _J =	: +25°C		2		V
R _O	Output Resistance ⁽¹⁰⁾	f = 1 kHz			17		mΩ
I _{SC}	Short-Circuit Current	$V_{I} = 35 \text{ V}, T_{A}$	= +25°C		250		mA
I _{PK}	Peak Current ⁽¹⁰⁾	T _J = +25°C			2.2		Α

- 9. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 10. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7810E)

Refer to test circuit, -40°C < T_J < 125°C, I_O = 500 mA, V_I = 16 V, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Symbol	Parameter	(Conditions	Min.	Тур.	Max.	Unit
		T _J = +25°C		9.6	10.0	10.4	
Vo	Output Voltage	$5.0 \text{ mA} \le I_O \le V_I = 12.5 \text{ V to}$	≤ 1.0 A, P _O ≤ 15 W, o 25 V	9.5	10.0	10.5	V
Regline	Line Regulation ⁽¹¹⁾	T _{.1} = +25°C	V _I = 12.5 V to 25 V		10	200	mV
Regilile	Line Regulation	1j = +25 C	V _I = 13 V to 25 V		3	100	IIIV
Dogland	Load Regulation ⁽¹¹⁾	T _{.1} = +25°C	$I_{O} = 5 \text{ mA to } 1.5 \text{ A}$		12	200	m\/
Regload	Load Regulation 7	1j = +25 C	$I_{O} = 250 \text{ mA to } 750 \text{ mA}$		4	400	mV
IQ	Quiescent Current	T _J = +25°C			5.1	8.0	mA
Al	Quiescent Current	$I_O = 5 \text{ mA to}$	1.0 A			0.5	mA
ΔI_{Q}	Change	V _I = 12.5 V to	29 V			1.0	I IIIA
$\Delta V_O/\Delta T$	Output Voltage Drift ⁽¹²⁾	$I_O = 5 \text{ mA}$			-1		mV/°C
V _N	Output Noise Voltage	f = 10 Hz to 10	00 kHz, T _A = +25°C		58		μV
RR	Ripple Rejection ⁽¹²⁾	f = 120 Hz, V	_I = 13 V to 23 V	56	71		dB
V_{Drop}	Dropout Voltage	I _O = 1 A, T _J =	: +25°C		2		V
R _O	Output Resistance ⁽¹²⁾	f = 1 kHz			17		mΩ
I _{SC}	Short-Circuit Current	$V_{I} = 35 \text{ V}, T_{A}$	= +25°C	_	250		mA
I _{PK}	Peak Current ⁽¹²⁾	T _J = +25°C			2.2		Α

- 11. Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 12. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7812E / KA7812ER)

Refer to test circuit, -40°C < T_J < 125°C, I_O = 500 mA, V_I = 19 V, C_I = 0.33 μ F, C_O= 0.1 μ F, unless otherwise specified.

Symbol	Parameter	(Conditions			Max.	Unit
		$T_J = +25^{\circ}C$		11.5	12.0	12.5	
Vo	Output Voltage	$5.0 \text{ mA } \leq I_{O}$ $V_{I} = 14.5 \text{ V to}$	≤ 1.0 A, P _O ≤ 15 W, o 27 V	11.4	12.0	12.6	V
Regline	Line Regulation ⁽¹³⁾	T _{.1} = +25°C	$V_I = 14.5 \text{ V to } 30 \text{ V}$		10	240	mV
ixegiirie	Line Regulation	11 - +23 0	V _I = 16 V to 22 V		3	120	111.0
Regload	Load Regulation ⁽¹³⁾	T _J = +25°C	$I_{O} = 5 \text{ mA to } 1.5 \text{ A}$		11	240	mV
Regioad	Load Regulation 7	1j = +25 C	$I_{O} = 250 \text{ mA to } 750 \text{ mA}$		5	120	IIIV
IQ	Quiescent Current	$T_J = +25^{\circ}C$	$T_J = +25^{\circ}C$		5.1	8.0	mA
Al	Quiescent Current	$I_O = 5 \text{ mA to}$	1.0 A		0.1	0.5	mA
ΔI_Q	Change	$V_{I} = 14.5 \text{ V to}$	o 30 V		0.5	1.0	IIIA
$\Delta V_O/\Delta T$	Output Voltage Drift ⁽¹⁴⁾	$I_O = 5 \text{ mA}$			-1		mV/°C
V_N	Output Noise Voltage	f = 10 Hz to 10	$00 \text{ kHz}, T_A = +25^{\circ}\text{C}$		76		μV
RR	Ripple Rejection ⁽¹⁴⁾	f = 120 Hz, V	' _I = 15 V to 25 V	55	71		dB
V_{Drop}	Dropout Voltage	$I_{O} = 1 \text{ A, T}_{J} =$	+25°C		2		V
R _O	Output Resistance ⁽¹⁴⁾	f = 1 kHz			18		mΩ
I _{SC}	Short-Circuit Current	$V_{I} = 35 \text{ V}, T_{A}$	√ = +25°C		230		mA
I _{PK}	Peak Current ⁽¹⁴⁾	$T_J = +25^{\circ}C$	_		2.2		Α

- 13. Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 14. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7815E)

Refer to test circuit, -40°C < T_J < 125°C, I_O = 500 mA, V_I = 23 V, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Symbol	Parameter	(Conditions			Max.	Unit
		$T_J = +25^{\circ}C$		14.40	15.00	15.60	
V _O	Output Voltage	$5.0 \text{ mA} \le I_0 \le V_1 = 17.5 \text{ V to}$	≤ 1.0 A, P _O ≤ 15 W, o 30 V	14.25	15.00	15.75	V
Regline	Line Regulation ⁽¹⁵⁾	T _{.1} = +25°C	$V_I = 17.5 \text{ V to } 30 \text{ V}$		11	300	mV
Regilile	Line Regulation	1j = +25 C	V _I = 20 V to 26 V		3	150	IIIV
Regload	Load Regulation ⁽¹⁵⁾	T _{.1} = +25°C	I _O = 5 mA to 1.5 A		12	300	mV
Regioad	Load Regulation 7	1j = +25 C	$I_{O} = 250 \text{ mA to } 750 \text{ mA}$		4	150	IIIV
ΙQ	Quiescent Current	$T_J = +25^{\circ}C$			5.2	8.0	mA
Al	Quiescent Current Change	$I_O = 5 \text{ mA to}$	1.0 A			0.5	mA
ΔI_{Q}	Quiescent Current Change	V _I = 17.5 V to 30 V				1.0	IIIA
$\Delta V_O/\Delta T$	Output Voltage Drift ⁽¹⁶⁾	$I_O = 5 \text{ mA}$			-1		mV/°C
V _N	Output Noise Voltage	f = 10 Hz to 10	00 kHz, T _A = +25°C		90		μV
RR	Ripple Rejection ⁽¹⁶⁾	f = 120 Hz, V	/ _I = 18.5 V to 28.5 V	54	70		dB
V_{Drop}	Dropout Voltage	I _O = 1 A, T _J =	: +25°C		2		V
R _O	Output Resistance ⁽¹⁶⁾	f = 1 kHz			19		mΩ
I _{SC}	Short-Circuit Current	$V_1 = 35 \text{ V}, T_A$	_λ = +25°C		250		mA
I _{PK}	Peak Current ⁽¹⁶⁾	T _J =+25°C			2.2		Α

- 15. Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 16. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7818E)

Refer to test circuit, -40°C < T_J < 125°C, I_O = 500 mA, V_I = 27 V, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Symbol	Parameter	C	Conditions	Min.	Тур.	Max.	Unit
		T _J =+25°C		17.3	18.0	18.7	
V _O	Output Voltage	$5.0 \text{ mA} \le I_0 \le V_1 = 21 \text{ V to } 3$	≤ 1.0 A, P _O ≤ 15 W, 33 V	17.1	18.0	18.9	V
Regline	e Line Regulation ⁽¹⁷⁾	T _{.J} = +25°C	V _I = 21 V to 33 V		15	360	mV
Regilile	Line Regulation 7	1j = +25 C	V _I = 24 V to 30 V		5	180	7 1117
Dogland	Load Regulation ⁽¹⁷⁾	T _J = +25°C	$I_{O} = 5 \text{ mA to } 1.5 \text{ A}$		15	360	m\/
Regload	Load Regulation 7	1j = +25 C	$I_{O} = 250 \text{ mA to } 750 \text{ mA}$		5	180	mV
IQ	Quiescent Current	T _J =+25°C	T _J =+25°C		5.2	8.0	mA
Al	Quiescent Current	$I_O = 5 \text{ mA to}$	1.0 A			0.5	mA
ΔI_{Q}	Change	V _I = 21 V to 33 V				1.0	IIIA
$\Delta V_{O}/\Delta T$	Output Voltage Drift ⁽¹⁸⁾	$I_O = 5 \text{ mA}$			-1		mV/°C
V _N	Output Noise Voltage	f = 10 Hz to 10	00 kHz, T _A = +25°C		110		μV
RR	Ripple Rejection ⁽¹⁸⁾	f = 120 Hz, V	' _I = 22 V to 32 V	53	69		dB
V_{Drop}	Dropout Voltage	I _O = 1 A, T _J =	+25°C		2		V
R _O	Output Resistance ⁽¹⁸⁾	f = 1 kHz			22		mΩ
I _{SC}	Short-Circuit Current	$V_{I} = 35 \text{ V}, T_{A}$	= +25°C		250		mA
I _{PK}	Peak Current ⁽¹⁸⁾	$T_J = +25^{\circ}C$			2.2		Α

- 17. Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 18. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7824E)

Refer to test circuit, -40°C < T_J < 125°C, I_O = 500 mA, V_I = 33 V, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Symbol	Parameter	(Conditions			Max.	Unit
		$T_J = +25^{\circ}C$		23.00	24.00	25.00	
Vo	Output Voltage	$5.0 \text{ mA} \le I_0 \le V_1 = 27 \text{ V to } 3$	≤ 1.0 A, P _O ≤ 15 W, 38 V	22.80	24.00	25.25	V
Regline	Line Regulation ⁽¹⁹⁾	T _{.1} = +25°C	V _I = 27 V to 38 V		17	480	mV
Regilile	Line Regulation	11 - +25 0	V _I = 30 V to 36 V		6	240	IIIV
Doglood	Load Regulation ⁽¹⁹⁾	T _{.1} = +25°C	$I_{O} = 5 \text{ mA to } 1.5 \text{ A}$		15	480	mV
Regload	Load Regulation 7	1j = +25 C	I _O = 250 mA to 750 mA		5	240	IIIV
IQ	Quiescent Current	$T_J = +25^{\circ}C$			5.2	8.0	mA
41	Quiescent Current	$I_O = 5 \text{ mA to}$	1.0 A		0.1	0.5	m ^
ΔI_{Q}	Change	$V_{I} = 27 \text{ V to } 3$	38 V		0.5	1.0 mA	ША
$\Delta V_{O}/\Delta T$	Output Voltage Drift ⁽²⁰⁾	$I_O = 5mA$			-1.5		mV/°C
V _N	Output Noise Voltage	f = 10 Hz to 10	00 kHz, T _A = +25°C		120		μV
RR	Ripple Rejection ⁽²⁰⁾	f = 120 Hz, V	' _I = 28 V to 38 V	50	67		dB
V_{Drop}	Dropout Voltage	I _O = 1 A, T _J =	+25°C		2		V
R _O	Output Resistance ⁽²⁰⁾	f = 1 kHz			28		mΩ
I _{SC}	Short-Circuit Current	$V_{I} = 35 \text{ V}, T_{A}$	= +25°C		230		mA
I _{PK}	Peak Current ⁽²⁰⁾	$T_J = +25^{\circ}C$			2.2		Α

- 19. Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 20. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7805AE)

Refer to the test circuit, 0° C < T_J < +125 $^{\circ}$ C, I_O = 1 A, V_I = 10 V, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Symbol	Parameter	Co	onditions	Min.	Тур.	Max.	Unit
		T _J =+25°C		4.9	5.0	5.1	
V _O	Output Voltage	$I_O = 5 \text{ mA to } 1$ $V_I = 7.5 \text{ V to } 2$	A, P _O ≤ 15 W, 20 V	4.8	5.0	5.2	V
		$V_1 = 7.5 \text{ V to } 2$	5 V, I _O = 500 mA		5.0	50.0	
Regline	Line Regulation ⁽²¹⁾	$V_1 = 8 \text{ V to } 12$	V		3.0	50.0	mV
Regilile	T _J = +25°C	V _I = 7.3 V to 20 V		5.0	50.0	IIIV	
		1j = +25 C	V _I = 8 V to 12 V		1.5	25.0	
		$T_J = +25^{\circ}C, I_O$	= 5 mA to 1.5 A		9	100	
Regload	Load Regulation ⁽²¹⁾	I _O = 5 mA to 1 A			9	100	mV
			$I_{O} = 250 \text{ mA to } 750 \text{ mA}$		4	50	
IQ	Quiescent Current	T _J = +25°C			5	6	mA
//		$I_O = 5 \text{ mA to } 1$	А			0.5	
ΔI_{Q}	Quiescent Current Change	$V_{I} = 8 \text{ V to } 25$	$V_{I} = 8 \text{ V to } 25 \text{ V}, I_{O} = 500 \text{ mA}$			0.8	mA
		$V_1 = 7.5 \text{ V to } 2$	0 V, T _J = +25°C			0.8	
ΔV/ΔΤ	Output Voltage Drift ⁽²²⁾	I _O = 5 mA			-0.8		mV/°C
V _N	Output Noise Voltage	f = 10 Hz to 10	00 kHz, T _A =+25°C		42		μV
RR	Ripple Rejection ⁽²²⁾		f = 120 Hz, I _O = 500 mA, V _I = 8 V to 18 V		68		dB
V_{Drop}	Dropout Voltage	$I_{O} = 1 \text{ A}, T_{J} = +25^{\circ}\text{C}$			2		V
R _O	Output Resistance ⁽²²⁾	f = 1 kHz			17		mΩ
I _{SC}	Short-Circuit Current	V _I = 35 V, T _A =	= +25°C		250		mA
I _{PK}	Peak Current ⁽²²⁾	$T_J = +25^{\circ}C$			2.2		Α

- 21. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 22. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7809AE)

Refer to the test circuit, 0° C < T_J < +125 $^{\circ}$ C, I_O = 1 A, V_I = 15 V, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
		$T_J = +25$ °C	8.82	9.00	9.18	V
V _O	Output Voltage	$I_O = 5 \text{ mA to 1 A}, P_O \le 15 \text{ W},$ $V_I = 11.2 \text{ V to 24 V}$	8.65	9.00	9.35	
		$V_I = 11.7 \text{ V to } 25 \text{ V}, I_O = 500 \text{ mA}$		6	90	
Regline	Line Regulation ⁽²³⁾	V _I = 12.5 V to 19 V		4	45	mV
rxegiirie		$T_J = +25^{\circ}C$ $V_I = 11.5 \text{ V to } 24 \text{ V}$ $V_I = 12.5 \text{ V to } 19 \text{ V}$		6	90	1110
		$V_1 = 12.5 \text{ V to } 19 \text{ V}$		2	45	
	(23)	$T_J = +25^{\circ}C$, $I_O = 5$ mA to 1.0 A		12	100	
Regload	Load Regulation ⁽²³⁾	I _O = 5 mA to 1.0 A		12	100	mV
		I _O = 250 mA to 750 mA		5	50	
IQ	Quiescent Current	$T_J = +25^{\circ}C$		5	6	mA
		$V_I = 11.7 \text{ V to } 25 \text{ V}, T_J = +25^{\circ}\text{C}$			0.8	mA
ΔI_{Q}	Quiescent Current Change	$V_{I} = 12 \text{ V to } 25 \text{ V}, I_{O} = 500 \text{ mA}$			0.8	
		I _O = 5 mA to 1.0 A			0.5	
ΔV/ΔΤ	Output Voltage Drift ⁽²⁴⁾	I _O = 5 mA		-1		mV/°C
V _N	Output Noise Voltage	f = 10 Hz to 100 kHz, T _A = +25°C		58		μV
RR	Ripple Rejection ⁽²⁴⁾	f = 120 Hz, I _O = 500 mA, V _I = 12 V to 22 V		62		dB
V_{Drop}	Dropout Voltage	I _O = 1 A, T _J = +25°C		2		V
R _O	Output Resistance ⁽²⁴⁾	f = 1 kHz		17		mΩ
I _{SC}	Short-Circuit Current	V _I = 35 V, T _A = +25°C		250		mA
I _{PK}	Peak Current ⁽²⁴⁾	$T_J = +25^{\circ}C$		2.2		Α

- 23. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 24. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7810AE)

Refer to the test circuit, 0° C < T_J < +125 $^{\circ}$ C, I_O = 1 A, V_I = 16 V, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
		T _J =+25°C	9.8	10.0	10.2	V
V _O	Output Voltage	$I_O = 5$ mA to 1 A, $P_O \le 15$ W, $V_I = 12.8$ V to 25 V	9.6	10.0	10.4	
		$V_I = 12.8 \text{ V to } 26 \text{ V}, I_O = 500 \text{ mA}$		8	100	mV
Regline	Line Regulation ⁽²⁵⁾	V _I = 13 V to 20 V		4	50	
rvegiirie		$T_J = +25^{\circ}C$ $V_I = 12.5 \text{ V to } 25 \text{ V}$ $V_I = 13 \text{ V to } 20 \text{ V}$		8	100	IIIV
		$V_1 = 13 \text{ V to } 20 \text{ V}$		3	50	
	(25)	$T_J = +25^{\circ}C$, $I_O = 5$ mA to 1.5 A		12	100	
Regload	Load Regulation ⁽²⁵⁾	I _O = 5 mA to 1 mA		12	100	mV
		I _O = 250 mA to 750 mA		5	50	
IQ	Quiescent Current	$T_J = +25^{\circ}C$		5	6	mA
		I _O = 5 mA to 1.0 A			0.5	
ΔI_Q	Quiescent Current Change	$V_I = 12.8 \text{ V to } 25 \text{ V}, I_O = 500 \text{ mA}$			0.8	mA
		V _I = 13 V to 26 V, T _J = +25°C			0.5	
ΔV/ΔΤ	Output Voltage Drift ⁽²⁶⁾	I _O = 5 mA		-1		mV/°C
V _N	Output Noise Voltage	f = 10 Hz to 100 kHz, T _A = +25°C		58		μV
RR	Ripple Rejection ⁽²⁶⁾	f = 120 Hz, I _O = 500 mA, V _I = 14 V to 24 V		62		dB
V_{Drop}	Dropout Voltage	I _O = 1 A, T _J = +25°C		2		V
R _O	Output Resistance ⁽²⁶⁾	f = 1 kHz		17		mΩ
I _{SC}	Short-Circuit Current	V _I = 35 V, T _A = +25°C		250		mA
I _{PK}	Peak Current ⁽²⁶⁾	$T_J = +25^{\circ}C$		2.2		Α

- 25. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 26. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7812AE)

Refer to the test circuit, 0° C < T_J < +125 $^{\circ}$ C, I_O = 1 A, V_I = 19 V, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Symbol	Parameter	Conditions		Min.	Тур.	Max.	Unit
		$T_J = +25^{\circ}C$		11.75	12.00	12.25	V
V _O	Output Voltage	$I_O = 5 \text{ mA to 1 A}, P_O \le 15 \text{ W},$ $V_I = 14.8 \text{ V to 27 V}$		11.50	12.00	12.50	
		V _I = 14.8 V to 30 V, I _O = 500 mA			10	120	
Danling	Line Regulation ⁽²⁷⁾	V _I = 16 V to 22	2 V		4	120	mV
Regline	Line Regulation 7	T - 125°C	V _I = 14.5 V to 27 V V _I = 16 V to 22 V		10	120	
		1j = +25 C	V _I = 16 V to 22 V		3	60	
	(27)	$T_J = +25^{\circ}C$, $I_O = 5$ mA to 1.5 A			12	100	mV
Regload	Load Regulation ⁽²⁷⁾	I _O = 5 mA to 1.0 A			12	100	
		I _O = 250 mA to 750 mA			5	50	
IQ	Quiescent Current	T _J = +25°C			5.1	6.0	mA
//		$V_{I} = 15 \text{ V to } 3$	30 V, T _J = +25°C			0.8	
ΔI_{Q}	Quiescent Current Change	$V_{I} = 14 \text{ V to } 27 \text{ V}, I_{O} = 500 \text{ mA}$				0.8	mA
		$I_O = 5 \text{ mA to}$	1.0 A			0.5	
ΔV/ΔΤ	Output Voltage Drift ⁽²⁸⁾	I _O = 5 mA			-1		mV/°C
V _N	Output Noise Voltage	$f = 10 \text{ Hz to } 100 \text{ kHz}, T_A = +25^{\circ}\text{C}$			76		μV
RR	Ripple Rejection ⁽²⁸⁾	f = 120 Hz, I _O = 500 mA, V _I = 14 V to 24 V			60		dB
V _{Drop}	Dropout Voltage	$I_{O} = 1 \text{ A}, T_{J} = +25^{\circ}\text{C}$			2		V
R _O	Output Resistance ⁽²⁸⁾	f = 1 kHz			18		mΩ
I _{SC}	Short-Circuit Current	V _I = 35 V, T _A = +25°C			250		mA
I _{PK}	Peak Current ⁽²⁸⁾	$T_J = +25^{\circ}C$			2.2		Α

- 27. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 28. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7815AE)

Refer to the test circuit, 0° C < T_J < +125 $^{\circ}$ C, I_O = 1 A, V_I = 23 V, C_I = 0.33 μ F, C_O = 0.1 μ F, unless otherwise specified.

Symbol	Parameter	Co	nditions	Min.	Тур.	Max.	Unit
		T _J = +25°C		14.7	15.0	15.3	V
V _O	Output Voltage	$I_O = 5 \text{ mA to 1 A}, P_O \le 15 \text{ W},$ $V_I = 17.7 \text{ V to 30 V}$		14.4	15.0	15.6	
		V _I = 17.9 V to 30 V, I _O = 500 mA			10	150	
Regline	Line Regulation ⁽²⁹⁾	V _I = 20 V to 2	6 V		5	150	mV
ixegiirie		T 125°C	$V_I = 17.5 \text{ V to } 30 \text{ V}$ $V_I = 20 \text{ V to } 26 \text{ V}$		11	150	
		1 J = +25 C	V _I = 20 V to 26 V		3	75	
	1 15 1 (29)	$T_J = +25^{\circ}\text{C}$, $I_O = 5 \text{ mA to } 1.5 \text{ A}$ $I_O = 5 \text{ mA to } 1.0 \text{ A}$ $I_O = 250 \text{ mA to } 750 \text{ mA}$			12	100	mV
Regload	Load Regulation ⁽²⁹⁾				12	100	
					5	50	
IQ	Quiescent Current	T _J = +25°C			5.2	6.0	mA
		$V_I = 17.5 \text{ V to } 30 \text{ V}, T_J = +25^{\circ}\text{C}$				0.8	
ΔI_{Q}	Quiescent Current Change	$V_I = 17.5 \text{ V to } 30 \text{ V}, I_O = 500 \text{ mA}$				0.8	mA
		$I_{O} = 5 \text{ mA to } 1.0 \text{ A}$				0.5	
ΔV/ΔΤ	Output Voltage Drift ⁽³⁰⁾	I _O = 5 mA			-1		mV/°C
V _N	Output Noise Voltage	f = 10 Hz to 100 kHz, T _A = +25°C			90		μV
RR	Ripple Rejection ⁽³⁰⁾	f = 120 Hz, I _O = 500 mA, V _I = 18.5 V to 28.5 V			58		dB
V _{Drop}	Dropout Voltage	$I_{O} = 1 \text{ A}, T_{J} = +25^{\circ}\text{C}$			2		V
R _O	Output Resistance ⁽³⁰⁾	f = 1 kHz			19		mΩ
I _{SC}	Short-Circuit Current	V _I = 35 V, T _A = +25°C			250		mA
I _{PK}	Peak Current ⁽³⁰⁾	T _J = +25°C			2.2		Α

- 29. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 30. These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (KA7824AE)

Refer to the test circuit, $0^{\circ}\text{C} < \text{T}_{\text{J}} < +125^{\circ}\text{C}$, I_{O} =1 A, V_{I} = 33 V, C_{I} = 0.33 μF , C_{O} = 0.1 μF , unless otherwise specified.

Symbol	Parameter	Conditions		Min.	Тур.	Max.	Unit
	T _J = +25°C			23.5	24.0	24.5	V
V _O	Output Voltage	$I_O = 5 \text{ mA to 1 A, } P_O \le 15 \text{ W,}$ $V_I = 27.3 \text{ V to } 38 \text{ V}$		23.0	24.0	25.0	
		$V_{I} = 27 \text{ V to } 38 \text{ V}, I_{O} = 500 \text{ mA}$			18	240	
Danling	Line Regulation ⁽³¹⁾	$V_1 = 21 \text{ V to } 3$	33 V		6	240	mV
Regline		T - 125°C	$V_1 = 26.7 \text{ V to } 38 \text{ V}$ $V_1 = 30 \text{ V to } 36 \text{ V}$		18	240	
		1j = +25 C	V _I = 30 V to 36 V		6	120	
	(31)	$T_J = +25^{\circ}C$, $I_O = 5$ mA to 1.5 A			15	100	mV
Regload	Load Regulation ⁽³¹⁾	I _O = 5 mA to 1.0 A			15	100	
		I _O = 250 mA to 750 mA			7	50	
IQ	Quiescent Current	T _J = +25°C			5.2	6.0	mA
//		V _I = 27.3 V to	38 V, T _J = +25°C			0.8	
ΔI_{Q}	Quiescent Current Change	$V_{I} = 27.3 \text{ V to } 38 \text{ V}, I_{O} = 500 \text{ mA}$				0.8	mA
		$I_O = 5 \text{ mA to}$	1.0 A			0.5	
ΔV/ΔΤ	Output Voltage Drift ⁽³²⁾	I _O = 5 mA			-1.5		mV/°C
V _N	Output Noise Voltage	$f = 10 \text{ Hz to } 100 \text{ kHz}, T_A = +25^{\circ}\text{C}$			120		μV
RR	Ripple Rejection ⁽³²⁾	f = 120 Hz, I _O = 500 mA, V _I = 28 V to 38 V			54		dB
V_{Drop}	Dropout Voltage	I _O = 1 A, T _J = +25°C			2		V
R _O	Output Resistance ⁽³²⁾	f = 1 kHz			20		mΩ
I _{SC}	Short-Circuit Current	V _I = 35 V, T _A = +25°C			250		mA
I _{PK}	Peak Current ⁽³²⁾	$T_J = +25^{\circ}C$			2.2		Α

- 31. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.
- 32. These parameters, although guaranteed, are not 100% tested in production.

Typical Performance Characteristics

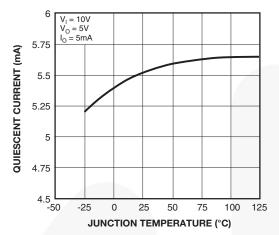


Figure 2. Quiescent Current

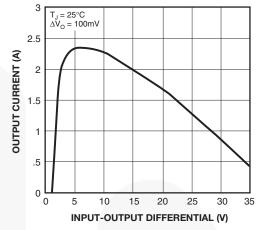


Figure 3. Peak Output Current

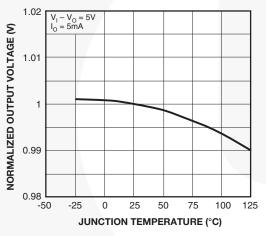


Figure 4. Output Voltage

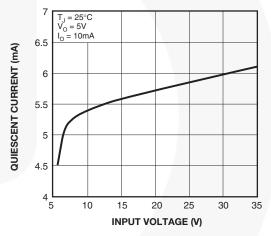


Figure 5. Quiescent Current

Typical Applications

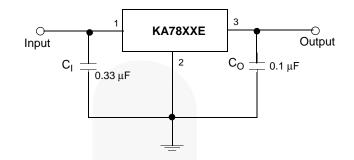


Figure 6. DC Parameters

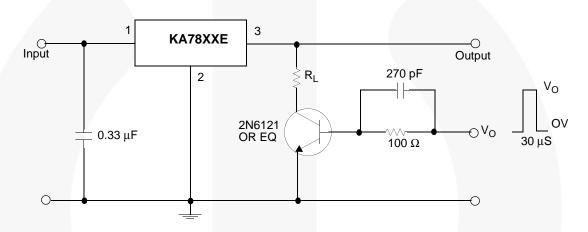


Figure 7. Load Regulation

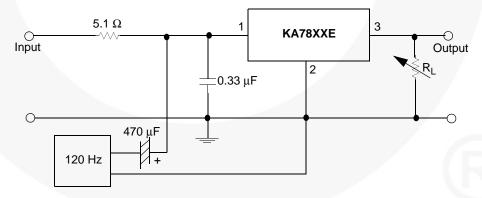


Figure 8. Ripple Rejection

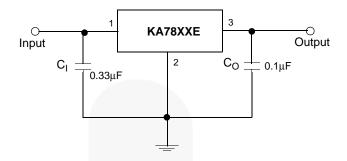


Figure 9. Fixed Output Regulator

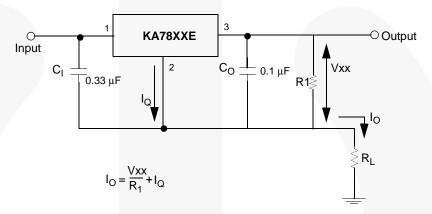
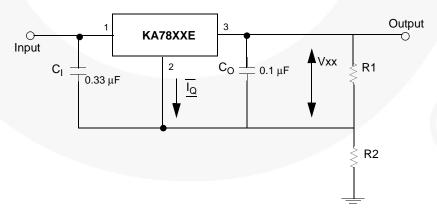


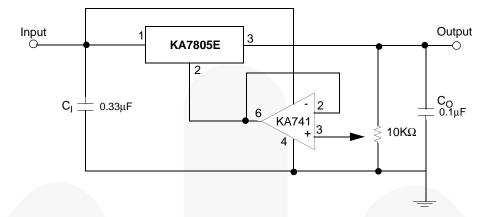
Figure 10. Constant Current Regulator

- 33. To specify an output voltage, substitute voltage value for "XX". A common ground is required between the input and the output voltage. The input voltage must remain typically 2.0 V above the output voltage even during the low point on the input ripple voltage.
- 34. C_I is required if regulator is located an appreciable distance from power supply filter.
- 35. C_O improves stability and transient response.



 $I_{RI} \ge 5IQ$ $V_{O} = V_{XX}(1+R_{2}/R_{1}) + I_{Q}R_{2}$

Figure 11. Circuit for Increasing Output Voltage



 $I_{RI} \ge 5 I_{Q}$ $V_{O} = V_{XX}(1+R_{2}/R_{1}) + I_{Q}R_{2}$

Figure 12. Adjustable Output Regulator (7 V to 30 V)

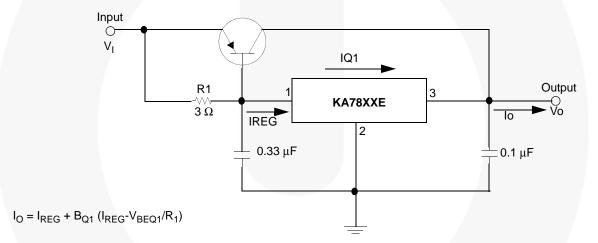


Figure 13. High-Current Voltage Regulator

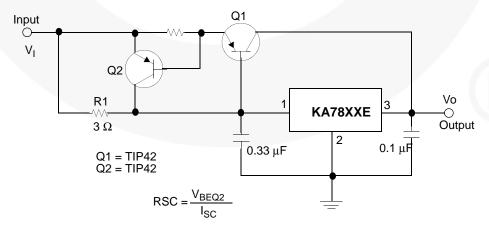


Figure 14. High Output Current with Short-Circuit Protection

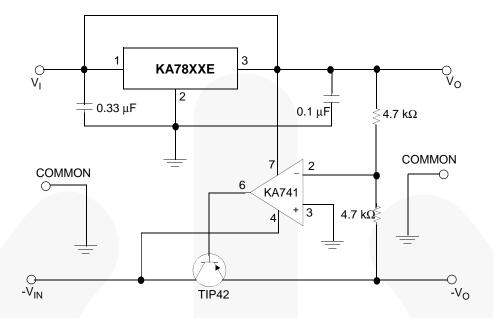


Figure 15. Tracking Voltage Regulator

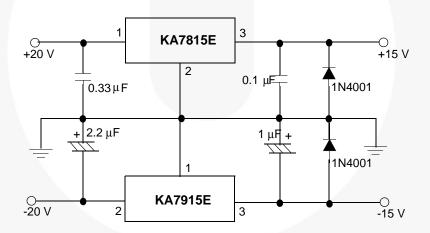


Figure 16. Split-Power Supply (±15 V - 1 A)

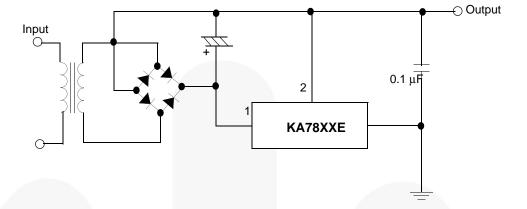


Figure 17. Negative Output Voltage Circuit

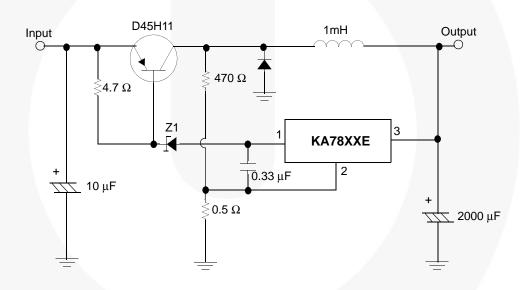


Figure 18. Switching Regulator

Physical Dimensions SUPPLIER "B" PACKAGE SHAPE Ø Ø4.00 3.50 10.67 SUPPLIER "A" PACKAGE 9.65<u>E</u> 3.40 2.50 IF PRESENT, SEE NOTE Ł 16.51 15.42 [2.46] C 14.04 12.70 FRONT VIEWS 1.62 1.42 OPTIONAL CHAMFER 6.69 6.06 <u></u> -NOTE "I" BOTTOM VIEW NOTES: IOLES: A) REFERENCE JEDEC, TO-220, VARIATION AB B) ALL DIMENSIONS ARE IN MILLIMETERS. C) DIMENSIONS COMMON TO ALL PACKAGE SUPPLIERS EXCEPT WHERE NOTED []. D) LOCATION OF MOLDED FEATURE MAY VARY 3 D) LOCATION OF MOLDED FEATURE MAY VARY (LOWER LEFT CORNER, LOWER CENTER AND CENTER OF THE PACKAGE) ENDOES NOT COMPLY JEDEC STANDARD VALUE. F) "A1" DIMENSIONS AS BELOW: SINGLE GAUGE = 0.51 - 0.61 DUAL GAUGE = 1.10 - 1.45 G) DRAWING FILE NAME: TOZZOBOJREV8 PRESENCE IS SUPPLIER DEPENDENT I) SUPPLIER DEPENDENT MOLD LOCKING HOLES IN HEATSINK. IN HEATSINK. J) FAIRCHILD SEMICONDUCTOR **BACK VIEW** SIDE VIEW

Figure 19. TO-220, MOLDED, 3-LEAD, NON-JEDEC, VARIATION AB (DUAL GUAGE)

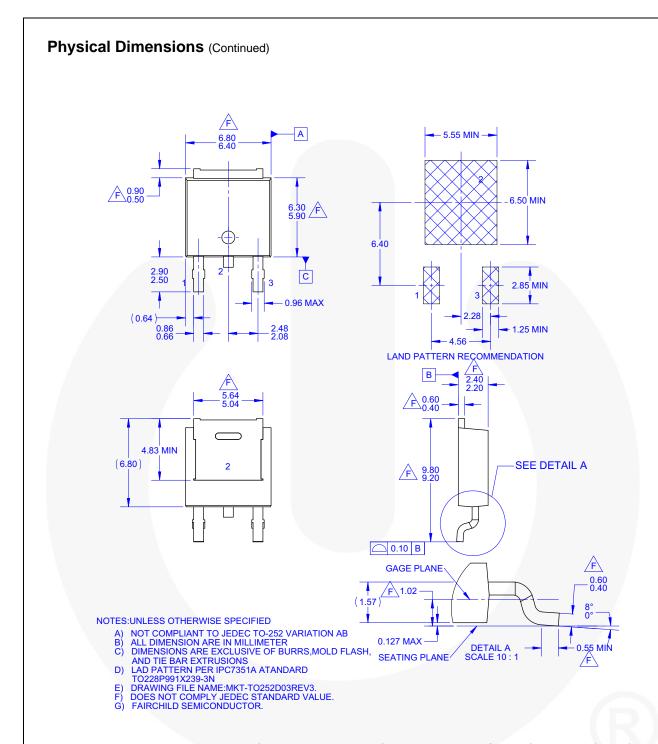


Figure 20. 3-LEAD, TO-252, NOT COMPLIANT TO JEDEC TO-252 VAR. AB, SURFACE MOUNT (DPAK)





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